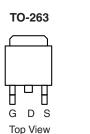
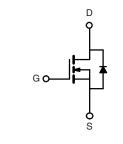


Automotive N-Channel 20 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	20			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 V$	0.0013			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 V$	0.0017			
I _D (A)	120			
Configuration	Single			





N-Channel MOSFET

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET
- Package with Low Thermal Resistance
- 100 % $R_{\rm q}$ and UIS Tested
- AEC-Q101 Qualified^d
- Compliant to RoHS Directive 2002/95/EC



ORDERING INFORMATION		
Package	TO-263	
Lead (Pb)-free and Halogen-free	SQM120N02-1m3L-GE3	

ABSOLUTE MAXIMUM RATINGS ($T_c = 25 \degree C$, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Voltage		V _{GS}	± 20	v	
Continuous Drain Current ^a	T _C = 25 °C	Ι _D	120		
Continuous Drain Current ^a	T _C = 125 °C		120		
Continuous Source Current (Diode Conduction) ^a	I _S	120	А		
Pulsed Drain Current ^b		I _{DM}	480		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	55		
Single Pulse Avalanche Energy		E _{AS}	150	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	D	375	W	
	T _C = 125 °C	P _D	125	vv	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to + 175	°C		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	40	°C/W	
Junction-to-Case (Drain)		R _{thJC}	0.4	0/10	

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.

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SQM120N02-1m3L



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SPECIFICATIONS ($T_c = 25$ °C, unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$		20	-	-	v	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	1.5	2.0	2.5	v	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 20 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 20 V, T _J = 125 °C	-	-	150	μA	
		$V_{GS} = 0 V$	V _{DS} = 20 V, T _J = 175 °C	-	-	500	μA	
On-State Drain Current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	120	-	-	А	
		$V_{GS} = 10 V$	I _D = 40 A	-	0.0011	0.0013		
Ducia Course On Otata Decistances		$V_{GS} = 10 V$	I _D = 40 A, T _J = 125 °C	-	-	0.0020	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}$	I _D = 40 A, T _J = 175 °C	-	-	0.0023		
		V _{GS} = 4.5 V	I _D = 35 A	-	0.0013	0.0017		
Forward Transconductance ^b	9 _{fs}	V _{DS}	= 15 V, I _D = 40 A	-	252	-	S	
Dynamic ^b					•	•	•	
Input Capacitance	C _{iss}		V _{DS} = 10 V, f = 1 MHz	-	11 538	14 500	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$		-	3598	4500		
Reverse Transfer Capacitance	C _{rss}			-	1385	1750		
Total Gate Charge ^c	Qg			-	192	290		
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V	V _{DS} = 10 V, I _D = 120 A	-	27	-	nC	
Gate-Drain Charge ^c	Q _{gd}				31	-	1	
Gate Resistance	R _g	f = 1 MHz		0.5	1.1	1.8	Ω	
Turn-On Delay Time ^c	t _{d(on)}	V_{DD} = 10 V, R _L = 0.084 Ω I _D ≅ 120 A, V _{GEN} = 10 V, R _g = 1 Ω		-	18	27		
Rise Time ^c	tr			-	11	17	- ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	64	96		
Fall Time ^c	t _f			-	12	18		
Source-Drain Diode Ratings and Characteristics ^b								
Pulsed Current ^a	I _{SM}			-	-	480	A	
Forward Voltage	V _{SD}	I _F =	-	0.8	1.5	V		

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

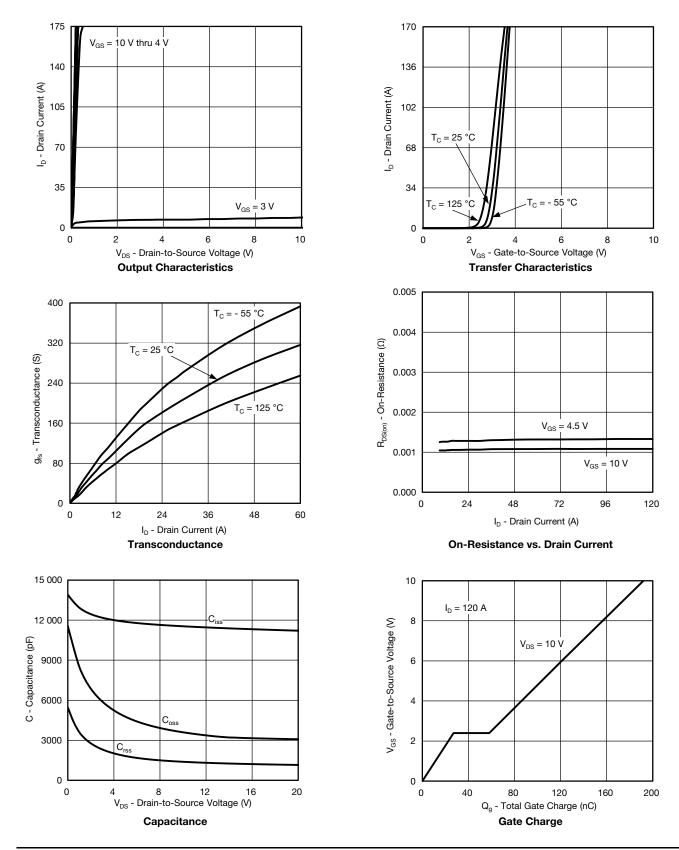
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



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Document Number: 63319

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T_{.1} = 25 °C

0.8

1.0

= 5 mA In I

I_D = 250 μÅ

50 75 100 125 150 175

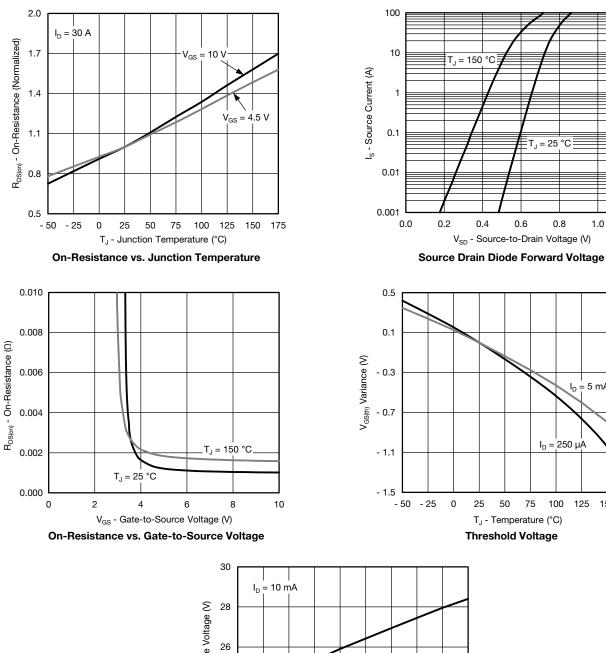
1.2

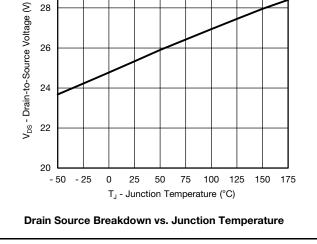
0.6



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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)





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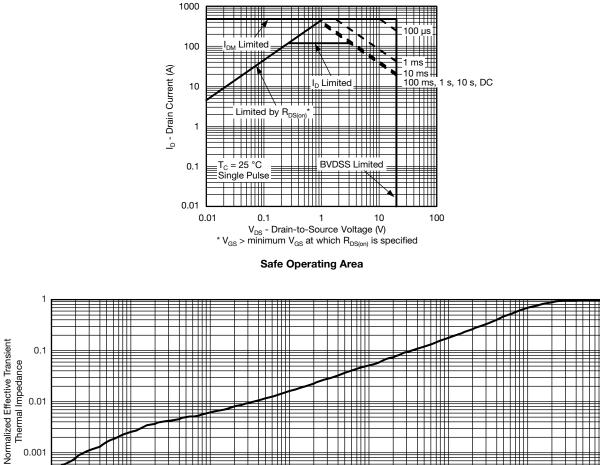
Document Number: 63319

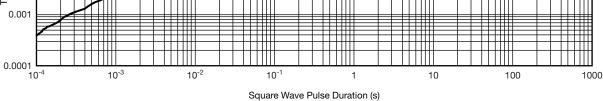


SQM120N02-1m3L

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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



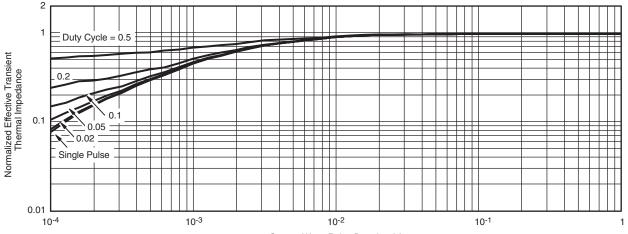


Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Square Wave Pulse Duration (s)

Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

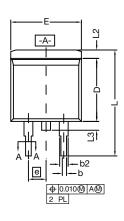
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

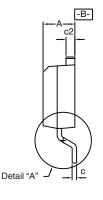
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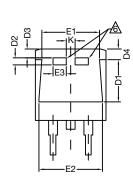


TO-263 (D²PAK): 3-LEAD

VERSION 1: FACILITY CODE = T

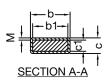








DETAIL A (ROTATED 90°)



		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017	9.525	
	E3 0.072		0.078	1.829	1.981	
е		0.100 BSC		2.54 BSC		
К		K 0.045		1.143	1.397	
L		L 0.575		14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		L3 0.050		1.270	1.778	
L4		0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	

Notes

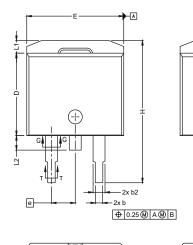
- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
- Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

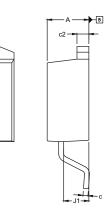
This feature is for thick lead.

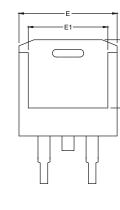
Revison: 28-Oct-2024

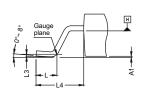


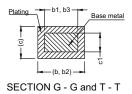
VERSION 2: FACILITY CODE = N











OPTION 1 2 leads



2

 \oplus

3 leads

DIM.	MIN.	MAX.		
A	4.36	4.56		
A1	0	0.25		
b	0.70	0.90		
b1	0.51	0.89		
b2	1.20	1.46		
b3	1.17	1.37		
с	0.38	0.694		
c1	0.38	0.534		
c2	1.19	1.34		
D	8.60	9.00		
D1	6.9	7.5		
E	10.15	10.55		
E1	8.1	8.7		
e	2.54 BSC			
Н	15.0	15.6		
L	1.9	2.5		
L1	-	1.65		
L2	-	1.78		
L3	0.25 typ.			
L4	4.78	5.28		
J1	2.56	2.96		
ECN: S24-1080-Rev. L, 28-Oct-2024 DWG: 5843				



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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